

View Online at <https://aerobasegroup.com/nsn/5961-01-356-4294>

**Inclosure Material:**

Metal all semiconductor device diode and ceramic all semiconductor device diode

**Overall Length:**

0.390 inches all semiconductor device diode

**Overall Diameter:**

0.104 inches all semiconductor device diode

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

6 semiconductor device diode

**Mounting Method:**

Press fit all semiconductor device diode

**Field Force Effect Type:**

Electrostatic charge

**Features Provided:**

Burn in and electrostatic sensitive and hermetically sealed case

**Semiconductor Material:**

Silicon all semiconductor device diode

**Voltage Rating In Volts Per Characteristic:**

35.0 breakdown voltage, dc all semiconductor device diode

**Capacitance Rating In Picofarads:**

3.4 all semiconductor device diode and 3.8 all semiconductor device diode

**Maximum Operating Temperature Per Measurement Point:**

150.0 degrees celsius junction all semiconductor device diode

**Terminal Type And Quantity:**

2 ferrule all semiconductor device diode

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

Yes - demil/mli

**Fiig:**

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